

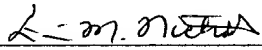


PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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|------------------|--|-----------------|-----------------------------|
| Applicant: | Hurkx et al. | Examiner: | Maldonado, J. |
| Application No.: | 09/854,403 | Group Art Unit: | 2823 |
| Filed: | May 11, 2001 | Docket No.: | PHN 16,741A (VLSI.411PA) |
| Title: | Semiconductor Device with a Bipolar Transistor, and Method of Manufacturing Such a Device | | |

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence and the papers, as described hereinabove, are being deposited in the United States Postal Service, as first class mail, in an envelope addressed to: Mail Stop RCE, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on December 21, 2004.

By: 
Erin M. Nichols

AMENDMENT WITH RCE

Mail Stop RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In further response to the final Office Action dated June 24, 2004, please consider the following amendment and remarks.

Amendments to the claims are reflected in the listing of claims beginning at page 2 and the Remarks begin on page 4.